

2024 MPW schedule

Last updated: June 19, 2024

MPW name	Fab	Processes	Tape-In	Ship Date
SB*18 - B5601	NPB - Fab 3	SiGe BiCMOS 0.18um	1-23-24	8-01-24
PH18MA - B5602	NPB - Fab 3	SiPho 0.18um	2-06-24	6-21-24
PH18DA - B5603	NPB - Fab 3	SiPho 0.18um	2-20-24	10-25-24
SB*18 - B5604	NPB - Fab 3	SiGe BiCMOS 0.18um	3-05-24	9-10-24
PH18M* - B5609	NPB - Fab 3	SiPho 0.18um	5-14-24	9-27-24
SB*18 - B5611	NPB - Fab 3	SiGe BiCMOS 0.18um	6-11-24	12-19-24
CS18* - B5608	MH - Fab 2	CMOS-SOI 0.18um	6-18-24	
31st MPW - Uozu, Japan	TPSCo - Fab 7	RFSOI, 65nm : TPS90RSB2, TPS65RSA2/RSB	7-08-24	
CA18 - B5613	NPB - Fab 3	RFCMOS 0.18um	7-16-24	12-27-24
SB*/CA13* - B5610	NPB - Fab 3	SiGe BiCMOS/RF CMOS 0.13um	7-30-24	3-28-25
SH424T18AUG	MH - Fab 2	CIS 0.18u Image Sensor CMOS+ 0.16u, 0.18u RF, RFID, PM	8-08-24 8-15-24	
SB*18 - B5615	NPB - Fab 3	SiGe BiCMOS 0.18um	8-13-24	2-20-25
PH18DA - B5614	NPB - Fab 3	SiPho 0.18um	8-20-24	4-25-25
30th MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	8-26-24	
PH18M* - B5617	NPB - Fab 3	SiPho 0.18um	9-10-24	1-24-25
32nd MPW - Uozu, Japan	TPSCo - Fab 7	CMOS,PM & RFCMOS, 65nm : TPS65SLA/SLC, TPS65PMA/PMB/MSA/MSB, TPS65RF	9-24-24	
SB*18 - B5619	NPB - Fab 3	SiGe BiCMOS 0.18um	10-8-24	4-17-25
CS18* - B5616	MH - Fab 2	CMOS-SOI 0.18um	10-22-24	
33rd MPW - Uozu, Japan	TPSCo - Fab 7	300mm Silicon Photonics: TPS45PHD	10-28-24	
CA18 - B5621	NPB - Fab 3	RFCMOS 0.18um	11-5-24	4-18-25
SH524T18NOV	MH - Fab 2	CIS 0.18u Image Sensor CMOS+ 0.16u, 0.18u RF, RFID, PM	11-14-24 11-21-24	
SB*18 - B5622	NPB - Fab 3	SiGe BiCMOS 0.18um	11-19-24	5-29-25
31st MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	11-25-24	

Notes: "Shuttles" (SH*) are run at Fab 2

* 0.13u MH – fab 2 Shuttle / MPW slots will be considered per needs

Please contact your customer account manager for additional information.

Fab2 - Tower Semiconductor 200mm wafer fabrication facility at Migdal Ha'emek, Israel

Fab3 - Tower Semiconductor 200mm wafer fabrication facility at Newport Beach, CA

Fab5 - Tower Semiconductor 200mm wafer fabrication facility at Tonami, Japan

Fab7 - Tower Semiconductor 300mm wafer fabrication facility at Uozu, Japan